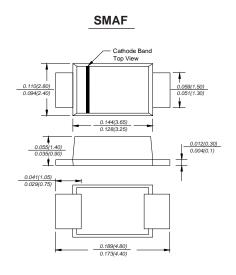


# **Your Reliable Components Partner**

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## ES1AAF THRU ES1JAF SURFACE MOUNT SUPER FAST RECTIFIER

## Reverse Voltage - 50 to 600 Volts Forward Current1-0 Ampere



Dimensions in inches and (millimeters)

#### **FEATURES**

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Super fast switching for high efficiency
- Low reverse leakage
- ◆ Built-in strain relief, ideal for automated placement
- High forward surge current capability
- High temperature soldering guarantéed: 260°C/10 seconds at terminals
- Glass passivated chip junction

### **MECHANICAL DATA**

**Case**: SMAF molded plastic body over passivated chip **Terminals**: Solder plated, solderable per MIL-STD-750,

Method 2026

Polarity: Color band denotes cathode end

**Mounting Position**: Any

Weight: 0.0014 ounce, 0.038 grams

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

	SYMBOLS	ES1AAF	ES1BAF	ES1CAF	ES1DAF	ES1EAF	ES1GAF	ES1JAF	UNITS
Maximum repetitive peak reverse voltage	VRRM	50	100	150	200	300	400	600	V
Maximum RMS voltage	VRMS	35	70	105	140	210	280	420	V
Maximum DC blocking voltage	VDC	50	100	150	200	300	400	600	V
Maximum average forward rectified current at TL=110℃	l <sub>(AV)</sub>	1.0							А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	lfsm	30.0						А	
Maximum instantaneous forward voltage at 1.0A	VF	0.95			1.	25	1.7	V	
Maximum DC reverse current Ta=25℃ at rated DC blocking voltage Ta=125℃	lr	5.0 50.0						μА	
Maximum reverse recovery time (NOTE 1)	trr	35						ns	
Typical junction capacitance (NOTE 2)	Cı	15.0						pF	
Typical thermal resistance (NOTE 3)	RθJA	88.0						°C/W	
Operating junction and storage temperature range	ТЈ,Тѕтс	-55 to +150							°C

Note: 1. Reverse recovery condition IF=0.5A, IR=1.0A, Irr=0.25A

2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

3.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas



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## RATINGS AND CHARACTERISTIC CURVES ES1AAF THRU ES1JAF

